



SANYO Semiconductors

## DATA SHEET

# 2SC6043

 — NPN Epitaxial Planar Silicon Transistors  
**High-Current Switching Applications**

## Applications

- Voltage regulators, relay drivers, lamp drivers, electrical equipment.

## Features

- Adoption of MBIT process.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.

## Specifications

### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		80	V
Collector-to-Emitter Voltage	V <sub>CES</sub>		80	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		6	V
Collector Current	I <sub>C</sub>		2	A
Collector Current (Pulse)	I <sub>CP</sub>		4	A
Base Current	I <sub>B</sub>		400	mA
Collector Dissipation	P <sub>C</sub>		1	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =40V, I <sub>E</sub> =0A			1	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =4V, I <sub>C</sub> =0A			1	μA
DC Current Gain	h <sub>FE1</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =100mA	200		560	
	h <sub>FE2</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =1.5A	40			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =300mA		420		MHz
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, f=1MHz		9		pF

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# 2SC6043

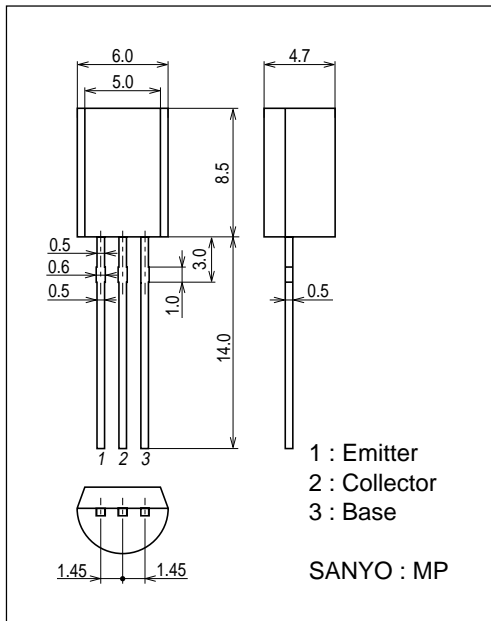
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1A, I_B=50mA$		150	300	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1A, I_B=50mA$		0.94	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CES}$	$I_C=100\mu A, R_{BE}=0\Omega$	80			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	6			V
Turn-ON Time	$t_{on}$	See specified Test Circuit.		35		ns
Storage Time	$t_{stg}$	See specified Test Circuit.		330		ns
Fall Time	$t_f$	See specified Test Circuit.		40		ns

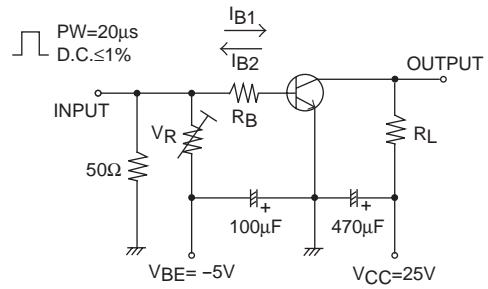
## Package Dimensions

unit : mm

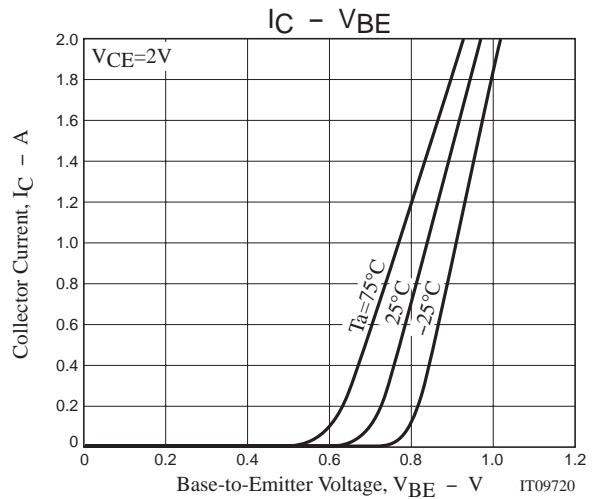
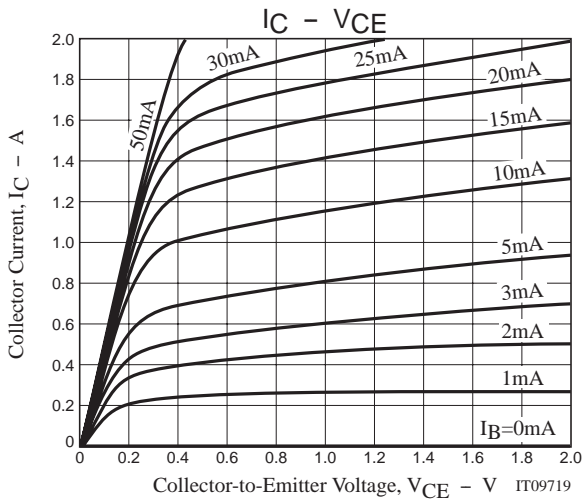
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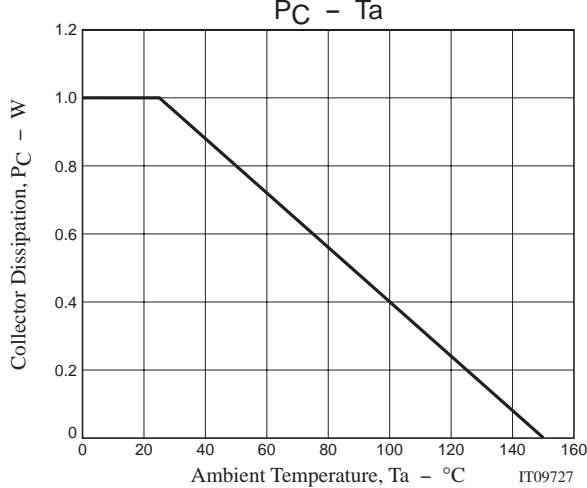
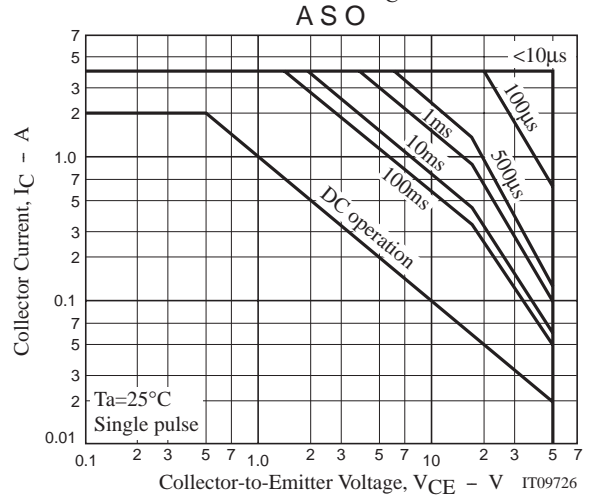
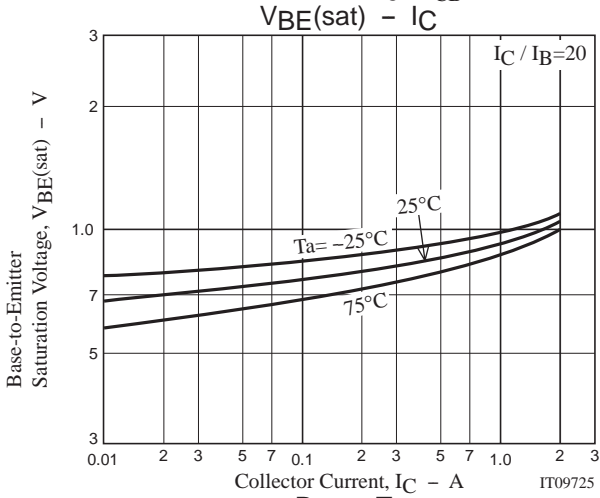
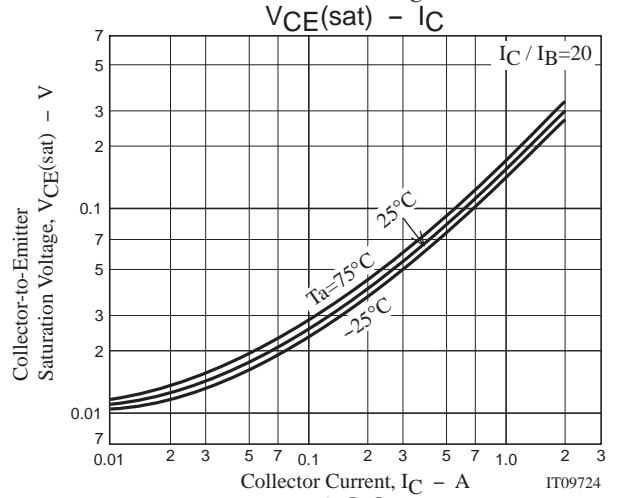
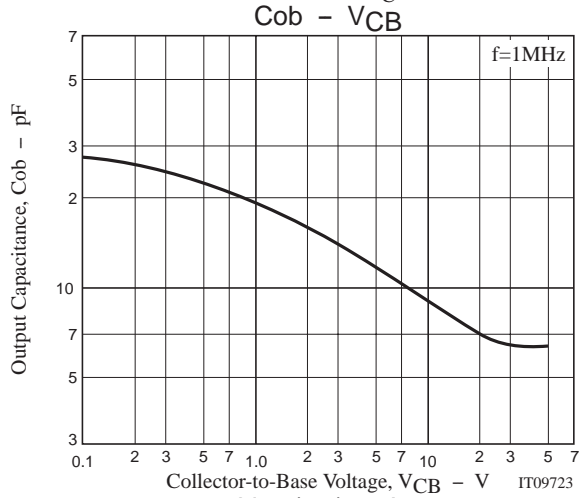
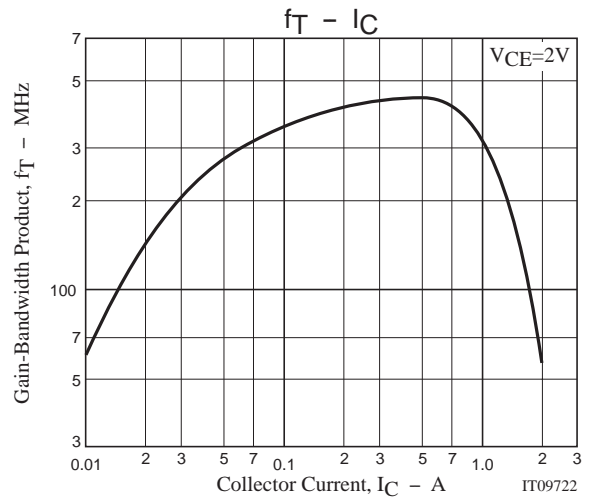
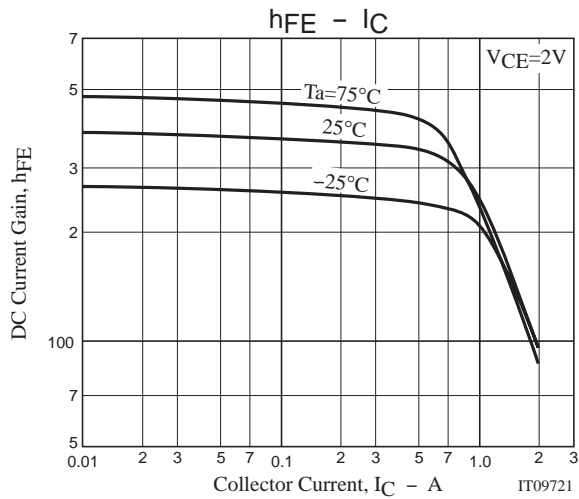
## Switching Time Test Circuit



$$I_C = 10I_{B1} = -10I_{B2} = 700mA$$



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